MOSFET – Power, Single, **N-Channel, DPAK** 40 V, 101 A

Features

- Low R_{DS(on)} to Minimize Conduction Losses
- Low Capacitance to Minimize Driver Losses
- Optimized Gate Charge to Minimize Switching Losses
- MSL 1/260°C
- 100% Avalanche Tested
- NVD Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

Applications

- CPU Power Delivery
- DC-DC Converters
- Motor Driver

MAXIMUM RATINGS (T_{.1} = 25°C unless otherwise noted)

Param	Parameter				
Drain-to-Source Voltage	V _{DSS}	40	V		
Gate-to-Source Voltage			V _{GS}	±20	V
Continuous Drain Cur-		$T_{C} = 25^{\circ}C$	Ι _D	101	А
rent (R _{θJC}) (Note 1)		$T_C = 85^{\circ}C$		78	
Power Dissipation $(R_{\theta JC})$ (Note 1)	Steady	$T_C = 25^{\circ}C$	P _D	93.75	W
Continuous Drain Cur-	State	$T_A = 25^{\circ}C$	I _D	16.4	А
rent (R _{θJA}) (Note 1)		$T_A = 85^{\circ}C$		12.7	
Power Dissipation $(R_{\theta JA})$ (Note 1)		$T_A = 25^{\circ}C$	PD	2.5	W
Pulsed Drain Current	t _p =10μs	$T_A = 25^{\circ}C$	I _{DM}	300	А
Current Limited by Packa	Current Limited by Package $T_A = 25^{\circ}C$				
Operating Junction and S	Storage Te	mperature	T _J , T _{stg}	–55 to 175	°C
Source Current (Body Di	ode)		۱ _S	50	А
Drain to Source dV/dt	dV/dt	6.0	V/ns		
$ \begin{array}{l} \mbox{Single Pulse Drain-to-S} \\ \mbox{ergy (V}_{DD} = 32 \mbox{ V}, \mbox{V}_{GS} = \\ \mbox{L} = 0.3 \mbox{ mH}, \mbox{ I}_{L(pk)} = 40 \mbox{ A} \end{array} $	E _{AS}	240	mJ		
Lead Temperature for Sc (1/8" from case for 10 s)	oldering Pu	irposes	ΤL	260	°C

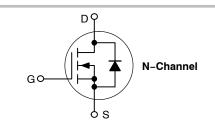
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



ON Semiconductor®

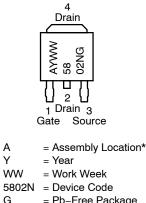
http://onsemi.com

V _{(BR)DSS}	R _{DS(on)}	I _D
40 V	4.4 mΩ @ 10 V	101 A
40 V	$7.8~\mathrm{m}\Omega @ 5.0~\mathrm{V}$	50 A





MARKING DIAGRAMS **& PIN ASSIGNMENT**



= Pb-Free Package

* The Assembly Location code (A) is front side optional. In cases where the Assembly Location is stamped in the package, the front side assembly code may be blank.

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

THERMAL RESISTANCE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Junction-to-Case (Drain)	$R_{ extsf{ heta}JC}$	1.6	°C/W
Junction-to-Ambient - Steady State (Note 1)	$R_{ hetaJA}$	60	
Junction-to-Ambient - Steady State (Note 2)	$R_{\theta JA}$	105	

1. Surface-mounted on FR4 board using 1 in sq pad size, 1 oz Cu.

2. Surface-mounted on FR4 board using the minimum recommended pad size.

ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise noted)

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
OFF CHARACTERISTICS						

Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	V_{GS} = 0 V, I_D = 10 μ A		40			V
Drain-to-Source Breakdown Voltage Temperature Coefficient	V _{(BR)DSS} /T _J				40		mV/°C
Zero Gate Voltage Drain Current	I _{DSS}	V _{GS} = 0 V,	$T_J = 25^{\circ}C$			1.0	μΑ
		V _{GS} = 0 V, V _{DS} = 40 V	T _J = 150°C			50	
Gate-to-Source Leakage Current	I _{GSS}	V_{DS} = 0 V, V_{GS} = ±20 V				±100	nA

ON CHARACTERISTICS (Note 3)

Gate Threshold Voltage	V _{GS(TH)}	V_{GS} = V_{DS} , I_D = 250 μ A	1.5		3.5	V
Negative Threshold Temperature Co- efficient	V _{GS(TH)} /T _J			-7.4		mV/°C
Drain-to-Source On Resistance	R _{DS(on)}	V_{GS} = 10 V, I _D = 50 A		3.6	4.4	mΩ
		V_{GS} = 5.0 V, I _D = 50 A		6.5	7.8	
Forward Transconductance	gFS	V _{DS} = 15 V, I _D = 15 A		16.8		S

CHARGES AND CAPACITANCES

Input Capacitance	C _{iss}		5300		pF
Output Capacitance	C _{oss}	V _{GS} = 0 V, f = 1.0 MHz, V _{DS} = 12 V	850		
Reverse Transfer Capacitance	C _{rss}		550		
Input Capacitance	C _{iss}	V _{GS} = 0 V, f = 1.0 MHz, V _{DS} = 25 V	5025		pF
Output Capacitance	C _{oss}	v _{DS} = 25 v	580		
Reverse Transfer Capacitance	C _{rss}		400		
Total Gate Charge	Q _{G(TOT)}		75	100	nC
Threshold Gate Charge	Q _{G(TH)}	V _{GS} = 10 V, V _{DS} = 15 V, I _D = 50 A	6.0		
Gate-to-Source Charge	Q _{GS}	I _D = 50 Å	18]
Gate-to-Drain Charge	Q _{GD}		15		

SWITCHING CHARACTERISTICS (Note 4)

Turn-On Delay Time	t _{d(on)}		14	ns
Rise Time	t _r	V _{GS} = 10 V, V _{DS} = 20 V,	52	
Turn-Off Delay Time	t _{d(off)}	$I_{\rm D} = 50 {\rm A}, {\rm R}_{\rm G} = 2.0 {\Omega}$	39	
Fall Time	t _f		8.5	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

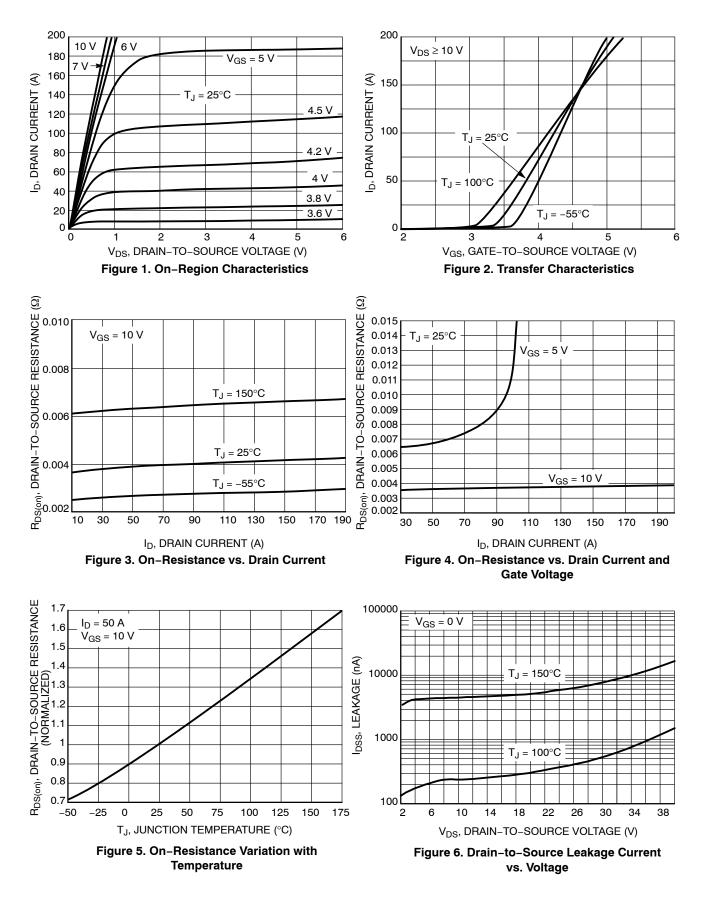
3. Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2%. 4. Switching characteristics are independent of operating junction temperatures.

ELECTRICAL CHARACTERISTICS ($T_J = 25^{\circ}C$ unless otherwise noted) (continued)

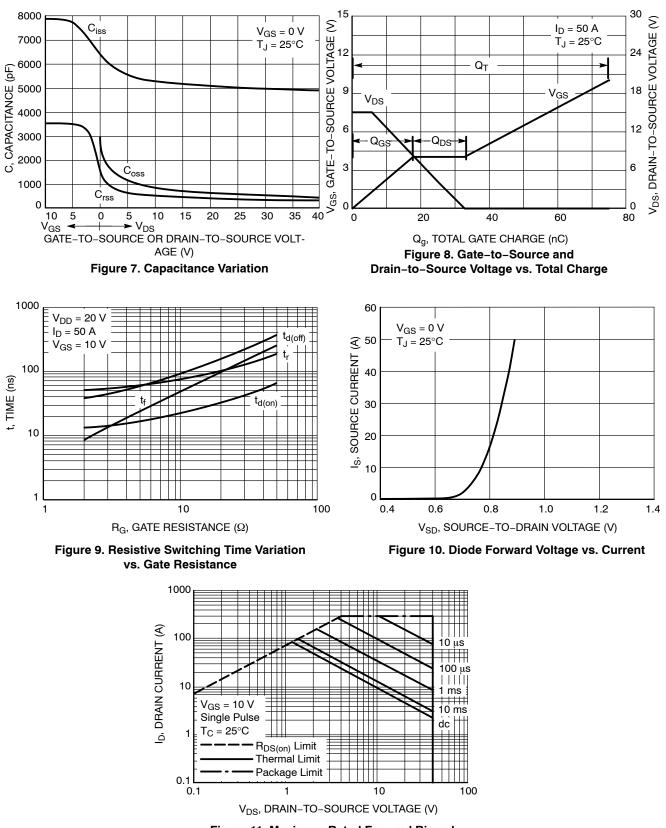
Parameter	Symbol	Test Cond	ition	Min	Тур	Max	Unit
DRAIN-SOURCE DIODE CHARACTERISTICS							
Forward Diode Voltage	V _{SD}	V _{GS} = 0 V, I _S = 50 A	T _J = 25°C		0.9	1.2	V
		V _{GS} = 0 V, I _S = 20 A	T _J = 25°C		0.8	1.0	
Reverse Recovery Time	t _{RR}				25		ns
Charge Time	ta	V _{GS} = 0 V, dls/dt	= 100 A/μs,		15		
Discharge Time	tb	V _{GS} = 0 V, dls/dt I _S = 50	A		10		1
Reverse Recovery Charge	Q _{RR}	1			15		nC

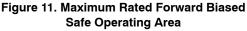
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.
Pulse Test: Pulse Width ≤ 300 µs, Duty Cycle ≤ 2%.
Switching characteristics are independent of operating junction temperatures.

TYPICAL PERFORMANCE CHARACTERISTICS



TYPICAL PERFORMANCE CHARACTERISTICS





TYPICAL PERFORMANCE CHARACTERISTICS

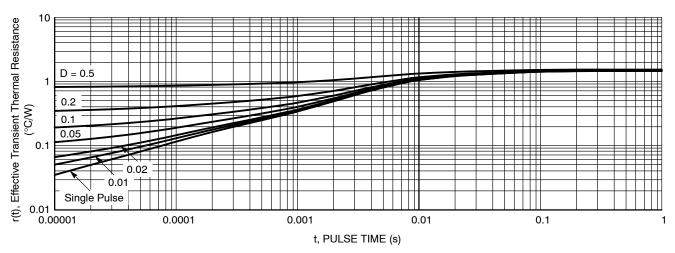


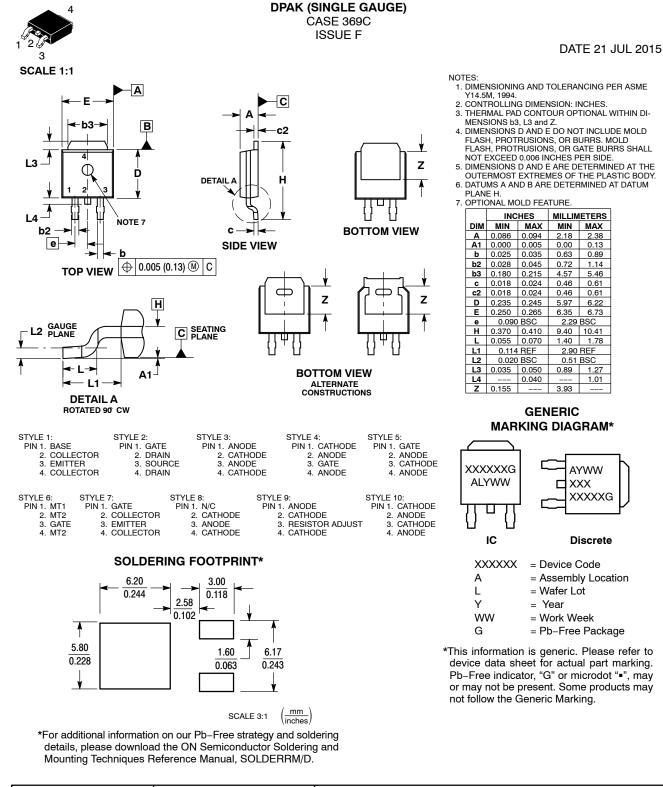
Figure 12. Thermal Response

ORDERING INFORMATION

Order Number	Package	Shipping [†]
NTD5802NT4G	DPAK (Pb-Free)	2500 / Tape & Reel
NVD5802NT4G*	DPAK (Pb-Free)	2500 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*NVD Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.



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